

# isc N-Channel MOSFET Transistor

# TK40E10N1, ITK40E10N1

### • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(on) ≤8.2mΩ. (V<sub>GS</sub> = 10 V)
- Enhancement mode:
  Vth =2.0 to 4.0V (VDS = 10 V, ID=0.5mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



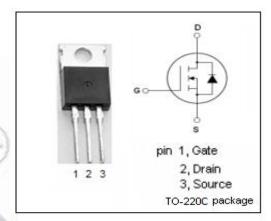
· Switching Voltage Regulators

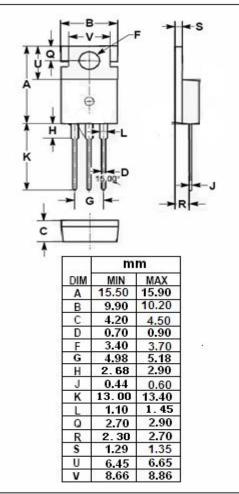
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	100	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	90	A	
I <sub>DM</sub>	Drain Current-Single Pulsed	171	Α	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	126	W	
Tj	Max. Operating Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}\! \mathbb{C}$	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.99	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	83.3	°C/W







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## **TK40E10N1, ITK40E10N1**

#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =10mA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.5mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =20A			8.2	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V	<b>1</b>		±0.1	μА
IDSS	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V			10	μА
$V_{SDF}$	Diode forward voltage	I <sub>DR</sub> =40A, V <sub>GS</sub> = 0 V			1.2	V

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